# **SR820 THRU SR8200**

# SCHOTTKY BARRIER RECTIFIER



REVERSE VOLTAGE: 20 to 200 VOLTS FORWARD CURRENT: 8.0 AMPERE

## **FEATURES**

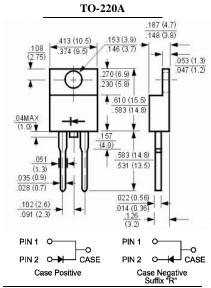
- · Plastic package has UL flammability classification 94V-0
- · Metal of silicon rectifier, majority carrier conduction
- · Guard ring for transient protection
- · High capability
- · Low power loss, high efficiency
- $\cdot$  High current capability, low  $V_{\text{F}}$
- · High surge capacity
- · For use in low voltage, high frequency inverters, free whelling, and polarity protection applications

#### **MECHANICAL DATA**

Case: Molded plastic, TO-220A Epoxy: UL 94V-O rate flame retardant

Terminals: Leads solderable per MIL-STD-202

method 208 guaranteed Polarity: As marked Mounting position: Any Weight: 0.08ounce, 2.24gram



Dimensions in inches and (millimeters)

# Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave,  $60H_Z$ , resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	SR820	SR830	SR840	SR850	SR860	SR880	SR8100	SR8150	SR8200	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	20	30	40	50	60	80	100	150	200	Volts
Maximum RMS Voltage	V <sub>RMS</sub>	14	21	28	35	42	56	70	105	140	Volts
Maximum DC Blocking Voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	150	200	Volts
Maximum Average Forward Rectified Current		8.0									Amp
See Fig. 1	$I_{(AV)}$										
Peak Forward Surge Current,											
8.3ms single half-sine-wave	$I_{FSM}$ 150									Amp	
superimposed on rated load (JEDEC method)											
Maximum Forward Voltage	V <sub>F</sub>		0.55		0	7	0	0.5	0.0	0.5	Volts
at 8.0A DC and 25℃	V <sub>F</sub>	0.55			0.7		0.85		0.95		Voits
Maximum Reverse Current at T <sub>C</sub> =25℃	$I_R$	1.0									A
at Rated DC Blocking Voltage $T_C=125$ °C	IR I	50			25						mAmp
Typical Junction Capacitance (Note 1)	$C_{J}$	700			460						pF
Typical Thermal Resistance (Note 2)	$R_{\theta JC}$	2.5									°C/W
Operating Temperature Range	$T_{J}$	-55 to +125							Ç		
Storage Temperature Range	Tstg	-55 to +150								Ç	

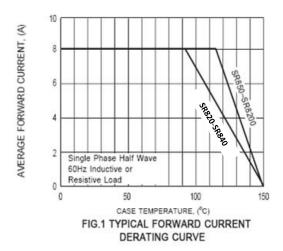
### NOTES:

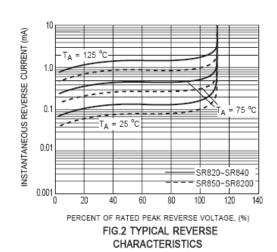
- 1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.
- 2- Thermal Resistance from Junction to Case Per Leg

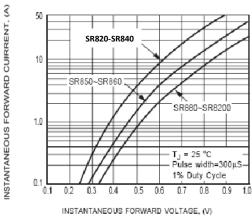




## RATINGS AND CHARACTERISTIC CURVES







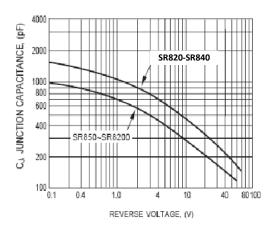
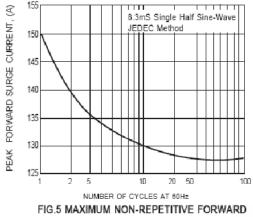


FIG.3 TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

FIG.4 TYPICAL JUNCTION CAPACITANCE



SURGE CURRENT